MOSPEC

S10L45

Switchmode Schottky Barrier Power Rectifiers

Using the Schottky Barrier principle with high temperature operation metal. The properitary barrier technology allows for reliable operation up to 150℃ junction temperature. Typical application are in switching Mode Power Supplies such as adaptators, Photovoltaic Solar cell protection,free-wheeling and polarity protection diodes.

SCHOTTKY BARRIER RECTIFIERS

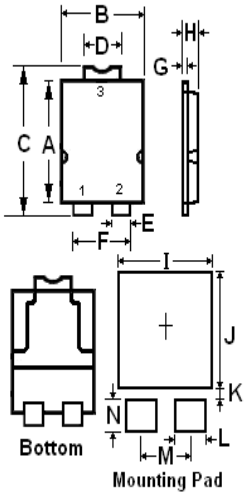
10 AMPERES 45VOLTS

TO-277

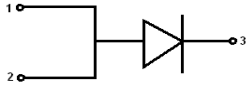
Features

- ＊Ultra Low Forward Voltage.
- ＊Low Switching noise.
- ＊High Current Capacity
- ＊Low Power Loss & High efficiency.
- ＊150℃ Operating Junction Temperature
- ＊Low Stored Charge Majority Carrier Conduction.
- ＊Plastic Material used Carries Underwriters Laboratory Flammability Classification 94V-O
- ＊ ESD: 4KV(Min.) Human-Body Model

＊*In compliance with EU RoHs 2002/95/EC directives*



DIM	MILLIMETERS	
	MIN	MAX
A	5.20	5.40
B	4.10	3.90
C	6.40	6.60
D	1.70	1.90
E	0.80	1.00
F	1.80	1.90
G	0.25	0.35
H	1.05	1.15
I	3.36	-----
J	4.86	-----
K	0.85	-----
L	1.40	-----
M	1.84	-----
N	1.40	-----



MAXIMUM RATINGS

Characteristic	Symbol	S10L45	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	45	V
RMS Reverse Voltage	$V_{R(RMS)}$	31.5	V
Average Rectifier Forward Current	$I_{F(AV)}$	10	A
Peak Repetitive Forward Current (Rate V_R, Square Wave, 20kHz)	I_{FM}	20	A
Non-Repetitive Peak Surge Current (Surge applied at rate load conditions halfware, single phase, 60Hz)	I_{FSM}	275	A
Operating and Storage Junction Temperature Range	T_J , T_{stg}	-65 to +150	℃

THERMAL RESISTANCES

Typical Thermal Resistance junction to case(per diode)	$R_{\theta j\text{-}c}$	10	℃/w

ELECTRIAL CHARACTERISTICS

Characteristic	Symbol	S10L45			Unit
Maximum Instantaneous Forward Voltage (per diode)	V_F	Min	Typ.	Max.	V
(I_F =0.1 Amp T_C = 25℃)		---	0.22	0.24	
(I_F =5.0 Amp T_C = 25℃)		---	0.38	0.40	
(I_F =10 Amp T_C = 25℃)		---	0.44	0.47	
Maximum Instantaneous Reverse Current	I_R				mA
(Rated DC Voltage, T_C = 25℃)			0.3		
(Rated DC Voltage, T_C = 125℃)			30		

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FIG-1 FORWARD CURRENT DERATING CURVE

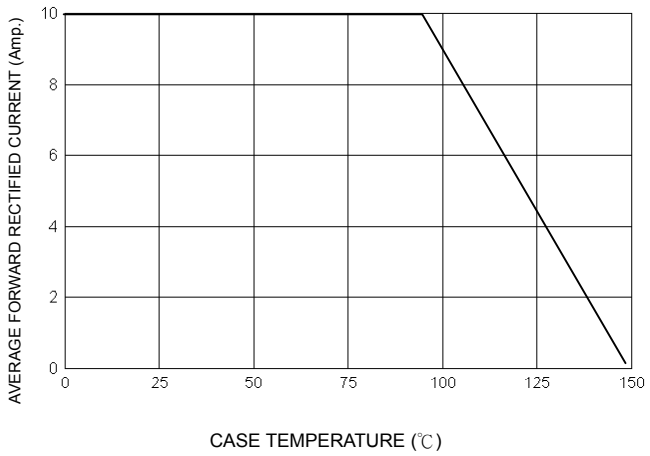


FIG-2 TYPICAL FORWARD CHARACTERISITICS

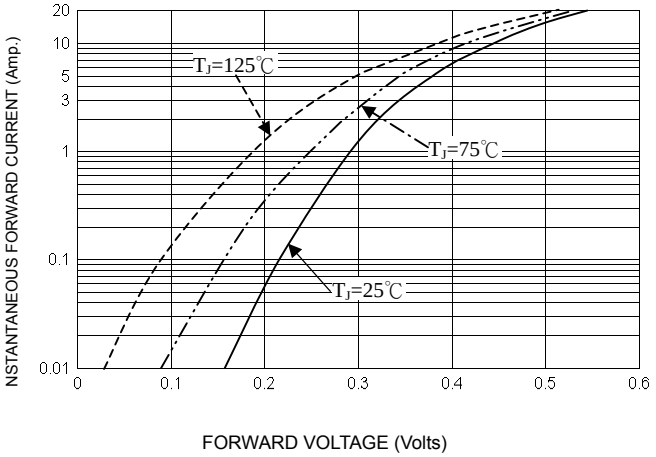


FIG-3 TYPICAL REVERSE CHARACTERISTICS

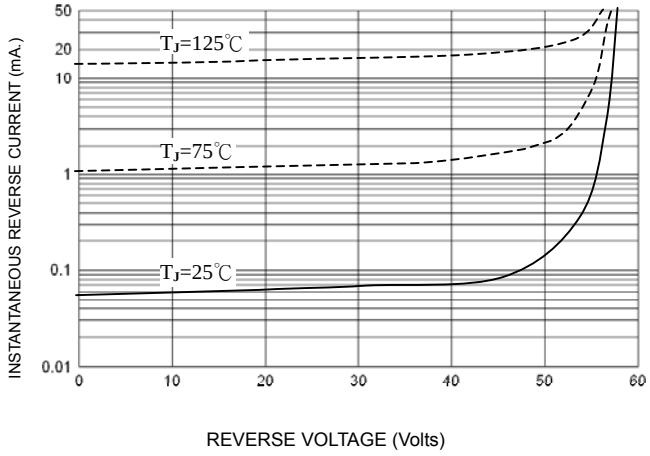


FIG-4 TYPICAL JUNCTION CAPACITANCE

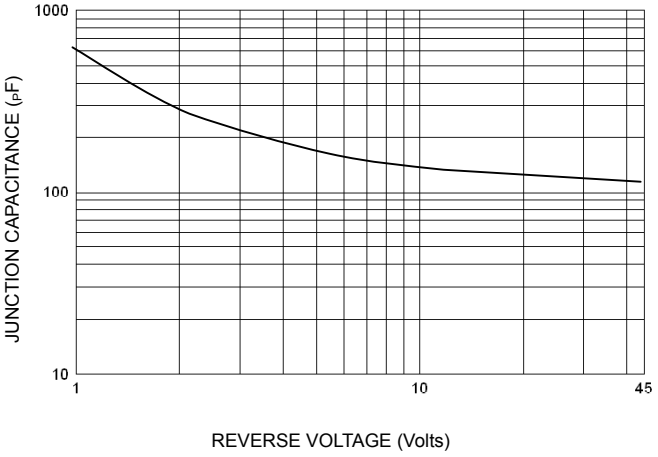
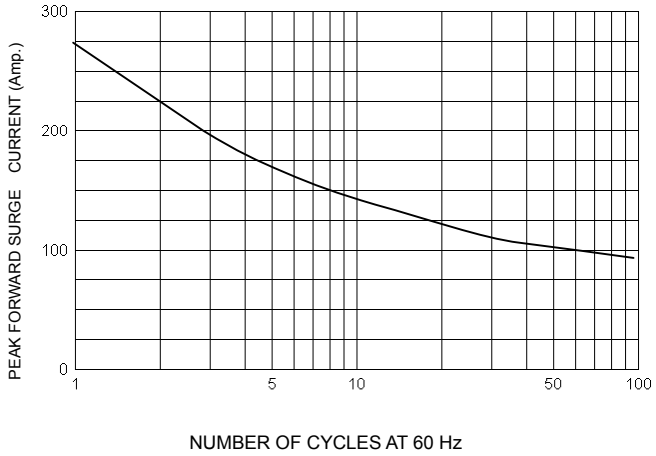


FIG-5 PEAK FORWARD SURGE CURRENT



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